

TED (15) - 3044(REVISION — 2015)

Reg. No.	
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## DIPLOMA EXAMINATION IN ENGINEERING/TECHNOLOGY/MANAGEMENT/COMMERCIAL PRACTICE — OCTOBER, 2018

## **ELECTRONIC DEVICES AND CIRCUITS**

[Time: 3 hours

(Maximum marks: 100)

PART — A

(Maximum marks: 10)

Marks

- I Answer all questions in one or two sentences. Each question carries 2 marks.
  - 1. State the need of multistage amplifier.
  - 2. Define Q factor.
  - 3. Define the term cross over distortion in power amplifier.
  - 4. Define pinch off voltage of a FET.
  - 5. List the merits of crystal oscillator.

 $(5 \times 2 = 10)$ 

## PART - B

(Maximum marks: 30)

- II Answer any five of the following questions. Each question carries 6 marks.
  - 1. Explain ac and dc load line with graph.
  - 2. List the advantage and disadvantage of direct coupled amplifier.
  - 3. A parallel tuned circuit is resonant at 455 KHz and has 20KHz band width and XL = 1500Kohm. Find Q factor.
  - 4. List the advantage of negative feedback.
  - 5. Explain the working of Unijunction transistor.
  - 6. Prove that the output of RC differentiator circuit is proportional to the derivative of the input.
  - 7. Explain the principle of L C oscillator.

 $(5 \times 6 = 30)$ 



Marks

## PART — C

(Maximum marks: 60)

(Answer one full question from each unit. Each full question carries 15 marks.)

		Unit — I		
III	(a)	Draw and explain the emitter follower and its application.	8	
	(b)	Distinguish between different coupling schemes used in multistage amplifiers.	7	
		OR		
IV	(a)	Draw the frequency response of Common Emitter RC coupled amplifier and explain why bandwidth decreases at low frequencies and high frequencies.	10	
	(b)	List the application of transformer coupled amplifier.	5	
		Unit — II		
V	(a)	Explain the classification of power amplifier with transfer characteristics curve.	8	
	(b)	Compare between series and parallel resonance circuit.	7	
		OR		
VI	(a)	Draw and Explain the operation of complementary symmetry push pull power amplifier.	9	
	(b)	Why heat sinks are necessary to use with power transistors.	6	
Unit — III				
VII	(a)	Describe construction of N-Channel deflection type MOSFET.	8	
	(b)	Distinguish the properties of positive and negative feedback circuits.	7	
		OR		
VIII	(a)	What are parameters of FET? Explain.	7	
	(b)	Distinguish between JFET and MOSFET.	8	
		Unit — IV		
IX	(a)	Draw and explain the working of Astable Multivibrator with waveforms.	7	
	(b)	Draw and explain the working of wein bridge oscillator.	8	
		OR		
X	(a)	Draw and explain working of collipts oscillator.	7	
	(b)	Explain the working of crystal oscillator, with neat circuit diagram.	8	